

<b>SPEC SHEET (FOR REFERENCE)</b>	SHEET No.	Rev.	Page.
	<b>G05057A</b>		1 of 1

TYPE : 6PT2106N4T\*\*

CHIP SIZE	0.38 * 0.38 mm
WAFER SIZE	6 inch
POSSIBLE DIE PER WAFER	106,200 pcs

Maximum Ratings(Ta=25°C)

Characteristics	Symbol	Ratings	Unit
Drain-source voltage	VDSS	60	V
Gate-source voltage	VGSS	±20	V
Drain Current (DC)	ID	0.3	A

\* For Reference

WAFER PROBING SPEC (Ta=25°C)

No	MODE	LIMIT				CONDITIONS
		MIN.	Typ	MAX.	UNIT	
1	IGSS			±10	nA	VGS= ±20V VDS= 0V
2	IDSS			1	uA	VDS= 60V VGS= 0V
3	BVDSS	63			V	ID= 10uA
4	VTH	0.8	1.2	1.6	V	ID= 250uA VDS=VGS
5	RDS(on)1		1	2.0	Ω	ID= 220mA VGS= 4.5V
6	RDS(on)2		0.9	1.6	Ω	ID= 220mA VGS= 10V
7	VSD	0.5		1.1	V	I= 115mA VGS= 0V

NOTE: